SQJ123ELP

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Vishay Siliconix

Automotive P-Channel 12 V (D-S) 175 °C MOSFET



PowerPAK[®] SO-8L

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

GC

P-Channel MOSFET



PRODUCT SUMMARY	
V _{DS} (V)	-12
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0040
$R_{DS(on)} (\Omega)$ at $V_{GS} = -2.5 V$	0.0064
I _D (A)	-238
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ123ELP (for detailed order number please see www.vishay.com/doc?79776)

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-12	- v	
Gate-source voltage ^a		V _{GS}	± 8		
Continuous drain ourrent	T _C = 25 °C ^b	I	-238		
Continuous drain current	T _C = 125 °C	ID	-137		
Continuous source current (diode conduction) b		Is	-340	А	
Pulsed drain current ^c		I _{DM}	400		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	73		
Single pulse avalanche energy		E _{AS}	270	mJ	
Maximum pawar dissinction 6	T _C = 25 °C	T _C = 25 °C		10/	
Maximum power dissipation ^c	T _C = 125 °C	P _D	125	W	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) ^{d, e}			260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^f	R _{thJA}	44	°C/W
Junction-to-case (drain)		R _{thJC}	0.4	0/11

Notes

a. Not intended for continuous use with positive gate voltage > 5.0 V

b. Package limited

- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 % f.

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For technical questions, contact: automostechsupport@vishay.com

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PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNIT
Static		•					
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = -250 μA		-12	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-0.45	-0.6	-1.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -12 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -12 V, T _J = 125 °C	-	-	-50	μA
		$V_{GS} = 0 V$	V _{DS} = -12 V, T _J = 175 °C	-	-	-150	
On-state drain current ^a	I _{D(on)}	V _{GS} = -4.5 V	$V_{DS} \ge -5 V$	-30	-	-	Α
		V _{GS} = -4.5 V	I _D = -10 A	-	0.0029	0.0040	
		$V_{GS} = -4.5 V$	I _D = -10 A, T _J = 125 °C	-	-	0.0057	1
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V	I _D = -10 A, T _J = 175 °C	-	-	0.0066	Ω
		V _{GS} = -2.5 V	I _D = -10 A	-	0.0040	0.0064	
		V _{GS} = -1.8 V	I _D = -8 A	-	0.0070	0.0012	
Forward transconductance b	9 _{fs}	V _{DS} = -6 V, I _D = -20 A		-	82	-	S
Dynamic ^b	•	•			•		
Input capacitance	C _{iss}			-	8342	11 680	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -6 V, f = 1 MHz	-	3173	4443	pF
Reverse transfer capacitance	C _{rss}			-	2844	3982	
Total gate charge ^c	Qg			-	120	180	
Gate-source charge ^c	Q _{gs}	V _{GS} = -4.5 V	V _{GS} = -4.5 V V _{DS} = -6 V, I _D = -15 A		15	-	nC
Gate-drain charge ^c	Q _{gd}			-	38	-	
Gate resistance	Rg		f = 1 MHz		2.2	3.3	Ω
Turn-on delay time ^c	t _{d(on)}			-	31	47	- ns
Rise time ^c	t _r	V _{DD} =	$V_{\text{DD}} = -6 \text{ V}, \text{ R}_{\text{L}} = 0.4 \Omega,$ $\text{I}_{\text{D}} \cong -15 \text{ A}, \text{ V}_{\text{GEN}} = -4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		53	80	
Turn-off delay time ^c	t _{d(off)}	I _D ≅ -15 Ā,			181	272	
Fall time ^c	t _f	1		-	126	189	
Source-Drain Diode Ratings and Char	acteristics ^b	•			•		
Pulsed current ^a	I _{SM}			-	-	-1360	Α
Forward voltage	V _{SD}	I _F =	-10 A, V _{GS} = 0 V	-	-0.76	-1.2	V
Body diode reverse recovery time	t _{rr}	I _F = -10 A, di/dt = 100 A/μs, V _{DD} = 9 V, R _L = 10 Ω, L = 0.1 mH		-	105	210	ns
Body diode reverse recovery charge	Q _{rr}			-	172	346	nC
Reverse recovery fall time	t _a			-	51	-	
Reverse recovery rise time	t _b			-	56	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-2.8	-	А

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

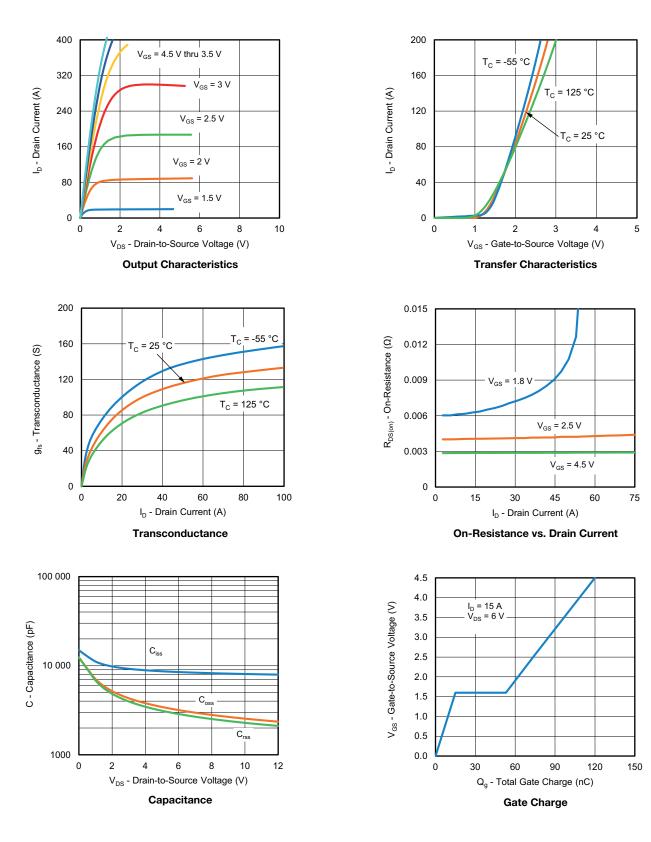
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2 For technical questions, contact: <u>automostechsupport@vishav.com</u> Document Number: 79217

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

100

10

1

0.1

0.01

0.7

0.5

0.3

0.1

-0.1

-0.3

1000

100

10

1

0.1

0.01

0.01

l_D - Drain Current (A)

-50 -25 0

V_{GS(th)} - Variance (V)

0

I_s - Source Current (A)

T, = 150 °C

0.2

0.4

T_J = 25 °C

0.6

V_{SD} - Source-to-Drain Voltage (V)

Source Drain Diode Forward Voltage

50

T_J - Junction Temperature (°C)

Threshold Voltage

25

mited

l imited

single pulse

0.1

DS(on)

111

1

V_{DS} - Drain-to-Source Voltage (V)

Safe Operating Area

I I KII

10

BVDSS limited

1.0

1.2

0.8

= 250 µA

= 5 mA I_D

75 100 125 150 175

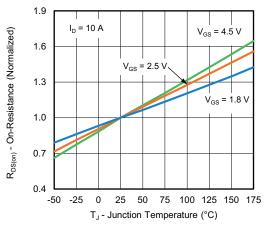
100 us

1 ms

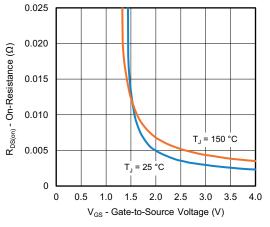
10 ms

100 ms

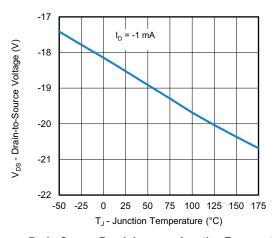
s, 10 s, DC



On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Drain-Source Breakdown vs. Junction Temperature

Note

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a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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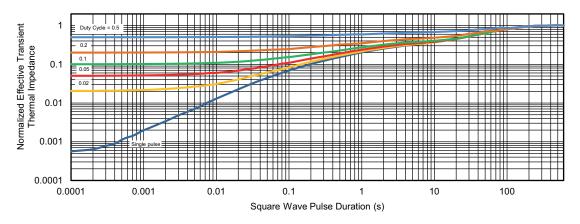
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100

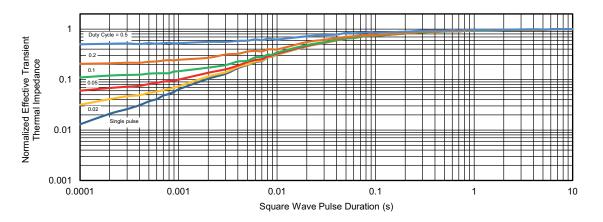
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THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

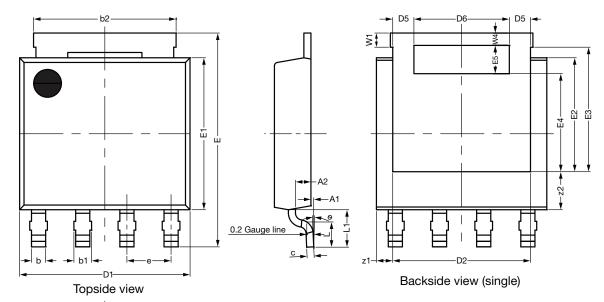
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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PowerPAK[®] SO-8L Case Outline 3



DIM.		MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
A2	0.40	0.45	0.50	0.016	0.018	0.020	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	
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Note

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• Millimeter will govern

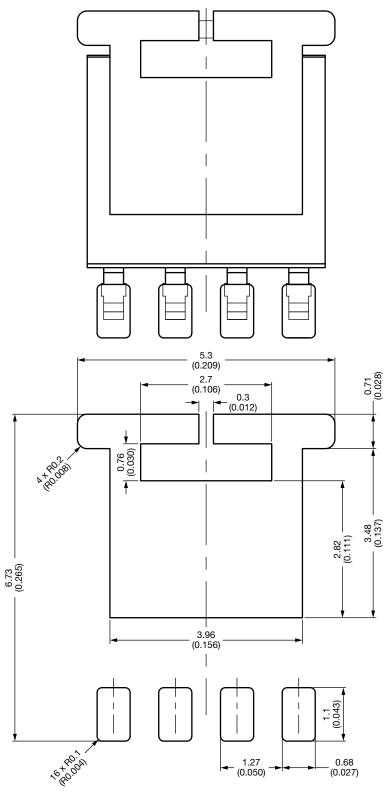
Revison: 05-Aug-2019

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Document Number: 76666



Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)

Revision: 24-Aug-2021



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